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# ZXMN0545G4

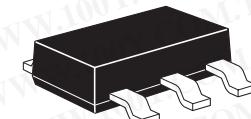
## 450V N-CHANNEL ENHANCEMENT MODE MOSFET

### SUMMARY

$V_{(BR)DSS} = 450V$ ;  $R_{DS(ON)} = 50\Omega$ ;  $I_D = 140mA$

### DESCRIPTION

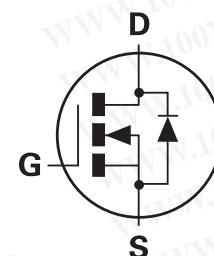
This 450V enhancement mode N-channel MOSFET provides users with a competitive specification offering efficient power handling capability, high impedance and is free from thermal runaway and thermally induced secondary breakdown. Applications benefiting from this device include a variety of Telecom and general high voltage circuits.



SOT223

### FEATURES

- High voltage
- Low on-resistance
- Fast switching speed
- Low gate drive
- Low threshold
- SOT223 package variant engineered to increase spacing between high voltage pins



### APPLICATIONS

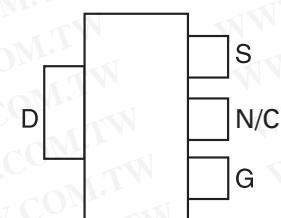
- Off-line power supply start-up circuitry

### ORDERING INFORMATION

DEVICE	REEL SIZE (inches)	TAPE WIDTH (mm)	QUANTITY PER REEL
ZXMN0545G4TA	7	12mm embossed	1,000 units
ZXMN0545G4TC	13	12mm embossed	4,000 units

### DEVICE MARKING

ZXMN  
0545



PINOUT - TOP VIEW

# ZXMN0545G4

## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	$V_{DS}$	450	V
Gate Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current ( $V_{GS}=10V$ ; $T_{amb}=25^\circ C$ ) <sup>(a)</sup>	$I_D$	140	mA
Pulsed Drain Current <sup>(c)</sup>	$I_{DM}$	600	mA
Continuous Source Current (Body Diode) <sup>(b)</sup>	$I_S$	140	A
Pulsed Source Current (Body Diode) <sup>(c)</sup>	$I_{SM}$	600	A
Power Dissipation at $T_{amb}=25^\circ C$ <sup>(a)</sup>	$P_{tot}$	2.0	W
Linear derating factor		1.6	mW/ $^\circ C$

## THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to Ambient <sup>(a)</sup>	$R_{\theta JA}$	62.5	$^\circ C/W$
Junction to Ambient <sup>(b)</sup>	$R_{\theta JA}$	32	$^\circ C/W$

### NOTES:

- (a) For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- (b) For a device surface mounted on FR4 PCB measured at  $t \leq 5$  secs.
- (c) Repetitive rating - pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph.



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## ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated)

PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS
Drain-Source Breakdown Voltage	$BV_{DSS}$	450		V	$I_D=1mA, V_{GS}=0V$
Gate-Source Threshold Voltage	$V_{GS(th)}$	1	3	V	$I_D=1mA, V_{DS}=V_{GS}$
Gate-Body Leakage	$I_{GSS}$		20	nA	$V_{GS} = \pm 20V, V_{DS}=0V$
Zero Gate Voltage Drain Current	$I_{DSS}$		10 400	$\mu A$ $\mu A$	$V_{DS}=450\text{ V}, V_{GS}=0V$ $V_{DS}=405\text{ V}, V_{GS}=0V,$ $T=125^\circ C$ (2)
On-State Drain Current <sup>(1)</sup>	$I_{D(on)}$	150		mA	$V_{DS}=25\text{ V}, V_{GS}=10V$
Static Drain-Source On-State Resistance <sup>(1)</sup>	$R_{DS(on)}$		50	$\Omega$	$V_{GS}=10V, I_D=100mA$
Forward Transconductance <sup>(1)(2)</sup>	$g_{fs}$	100		mS	$V_{DS}=25V, I_D=100mA$
Input Capacitance <sup>(2)</sup>	$C_{iss}$		70	pF	$V_{DS}=25V, V_{GS}=0V, f=1MHz$
Common Source Output Capacitance <sup>(2)</sup>	$C_{oss}$		10	pF	
Reverse Transfer Capacitance <sup>(2)</sup>	$C_{rss}$		4	pF	
Turn-On Delay Time <sup>(2)(3)</sup>	$t_{d(on)}$		7	ns	$V_{DD}=25V, I_D=100mA$
Rise Time <sup>(2)(3)</sup>	$t_r$		7	ns	
Turn-Off Delay Time <sup>(2)(3)</sup>	$t_{d(off)}$		16	ns	
Fall Time <sup>(2)(3)</sup>	$t_f$		10	ns	

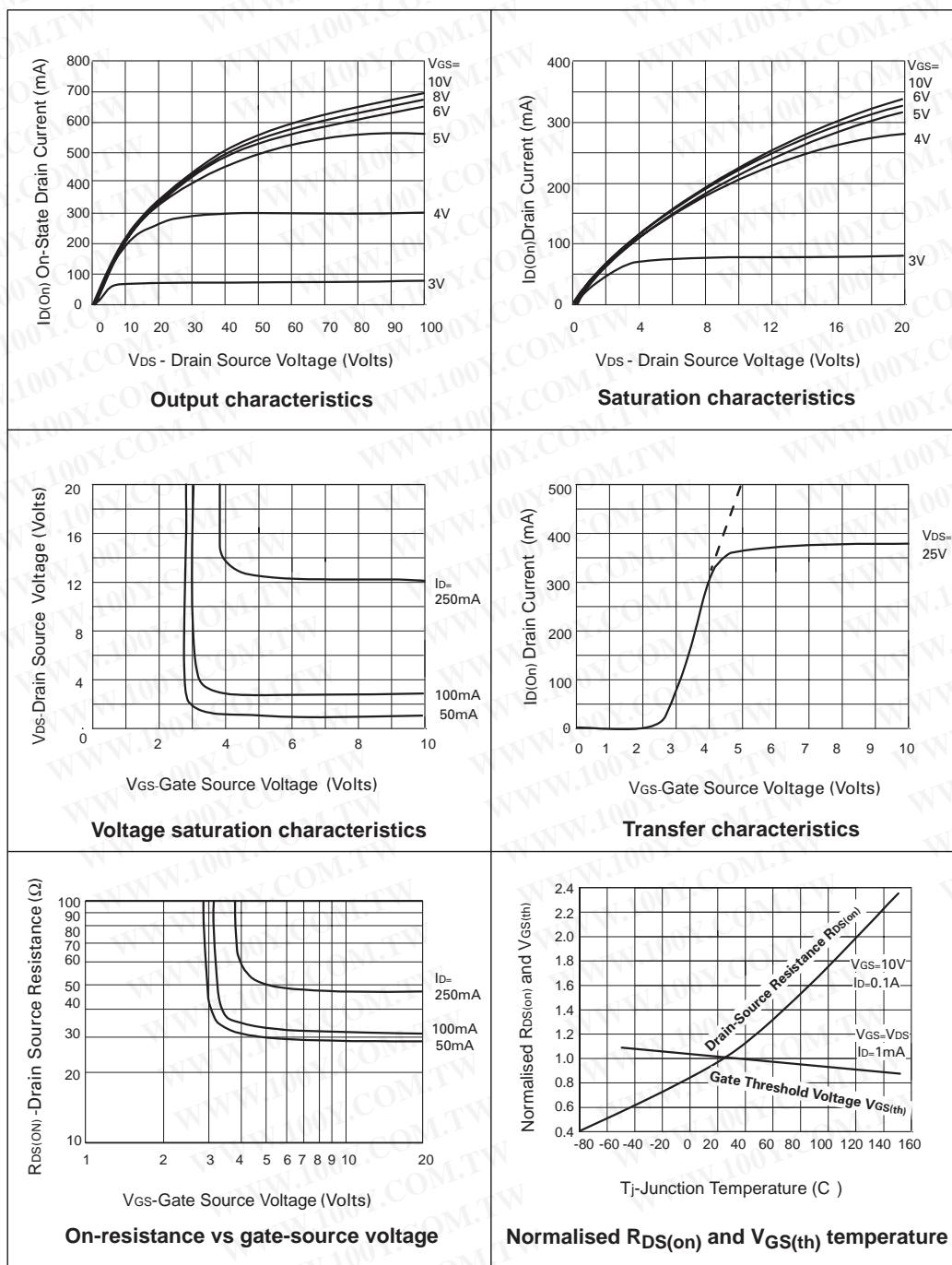
(1) Measured under pulsed conditions. Width=300 $\mu s$ . Duty cycle  $\leq 2\%$

(2) Sample test.

(3) Switching times measured with 50 $\Omega$  source impedance and <5ns rise time on a pulse generator

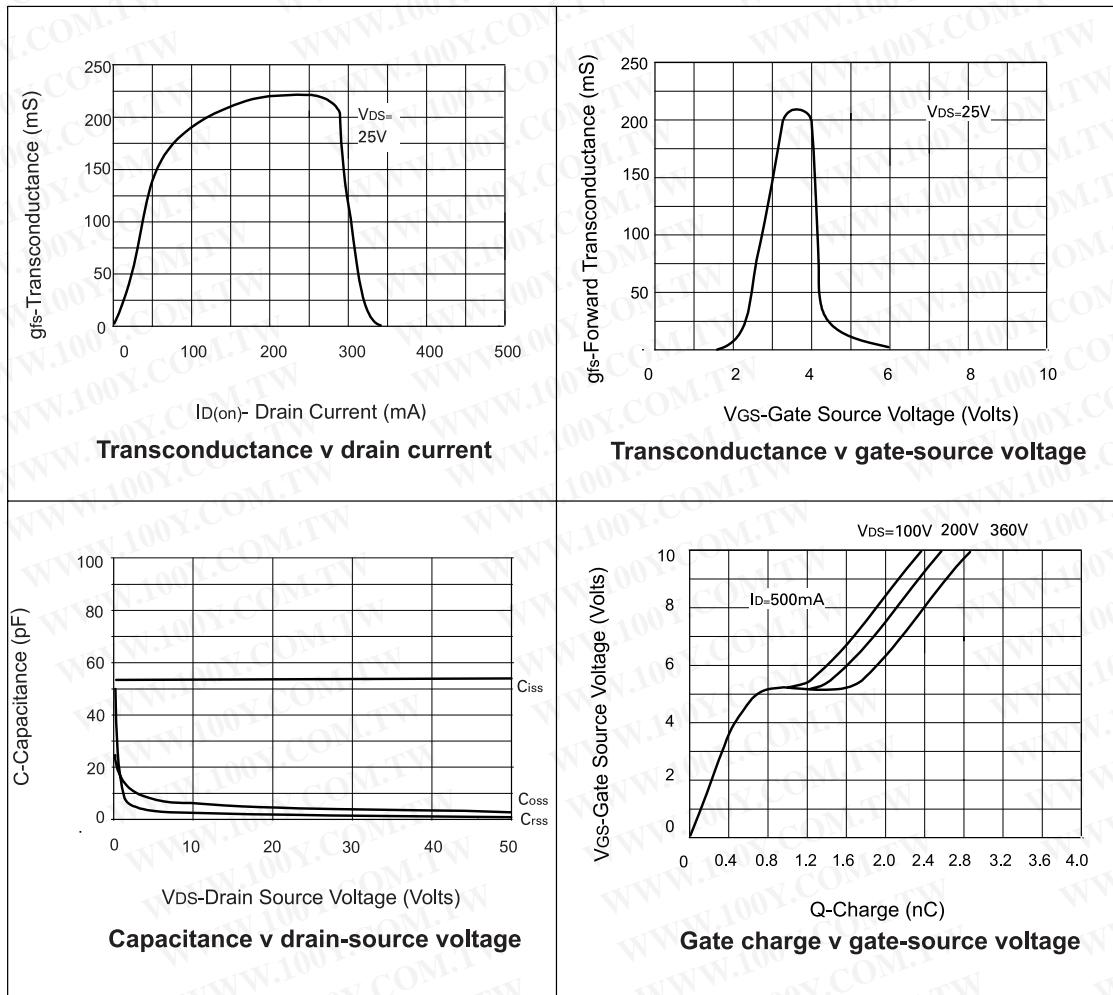
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## TYPICAL CHARACTERISTICS



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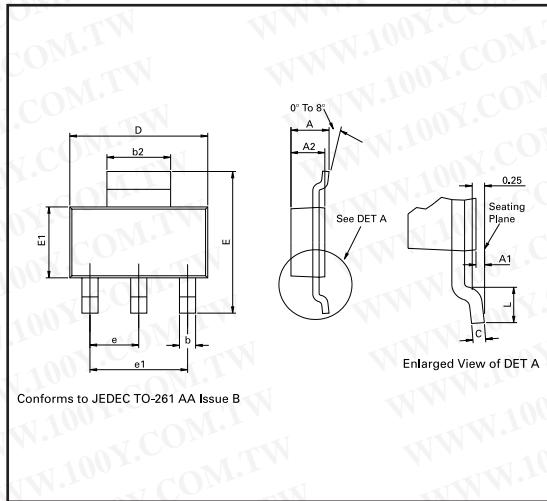
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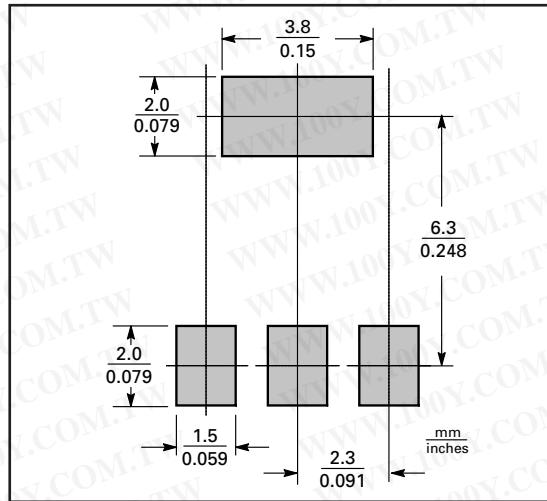
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## PACKAGE OUTLINE



## PAD LAYOUT DETAILS



Controlling dimensions are in millimeters. Approximate conversions are given in inches

## PACKAGE DIMENSIONS

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A	-	1.80	-	0.071	e	2.30	BSC	0.0905	BSC
A1	0.02	0.10	0.0008	0.004	e1	4.60	BSC	0.181	BSC
b	0.66	0.84	0.026	0.033	E	6.70	7.30	0.264	0.287
b2	2.90	3.10	0.114	0.122	E1	3.30	3.70	0.130	0.146
C	0.23	0.33	0.009	0.013	L	0.90	-	0.355	-
D	6.30	6.70	0.248	0.264	-	-	-	-	-